LED Shunt

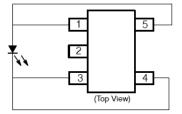
The HBL1015/25 Series are electronic shunts which provide a current bypass in the case of LEDs going into open circuit. LEDs are by nature quite fragile when subjected to transients and surge conditions. There are also many cases where high reliability of the LED lighting must be maintained such as in headlights, lighthouses, bridges, aircraft, runways and so forth. In these cases the low cost addition of the HBL device will provide full assurance that an entire string of LEDs will not extinguish should one LED fail open. The HBL device is also applicable to other loads where circuit continuity is required. The devices can be used with LED string currents from 140 to 500 mA.

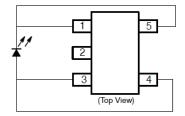
Features

- A Bidirectional Device
- Automatically Resets Itself if the LED Heals Itself or is Replaced
- ON-State Voltage Typically 1.8 V
- OFF-State Current less than 0.5 µA
- These are Pb-Free Devices

Typical Applications

- LEDs where Preventive Maintenance is Impractical
- LED Headlights
- LEDs with High Reliability Requirements
- Crowbar Protection for Open Circuit Conditions
- Overvoltage Protection for Sensitive Circuits





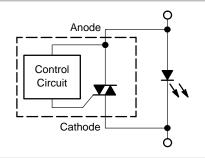
- 1. Device is bidirectional. Either configuration shown is acceptable.
- 2. Pin 2 must be electrically floating

Figure 1. Pin Connections



ON Semiconductor®

www.onsemi.com





TSOP-5 CASE 483

MARKING DIAGRAM



xxx = Specific Device Code (015 or 025)

M = Date Code= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
On–State Current, (T _A = 25°C) (Note 1) (Note 2) (Note 3)	I _{T(AVG)}	500 425 250	mA
Thermal Resistance, Junction–to–Air (Note 1) (Note 2) (Note 3)	θJA	140 150 255	°C/W
Operating Temperature Range	T_J	-40 to 150	°C
Non-Operating Temperature Range	TJ	150	°C
Lead Temperature, Soldering (10 Sec)	TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Mounted onto a 1500 mm², Denka K1, 1.5 mm Al, 2 kV thermally conductive dielectric, 2 oz. Cu, or equivalent board. Heat sinking should be spread equally among all pins (caution: pin 2 must be electrically isolated).

 2. Mounted onto a 2–layer, 1000 mm² per layer, 3 oz Cu, FR4 PCB. Heat sinking should be spread equally among all pins (caution: pin 2 must
- be electrically isolated).
- Mounted onto a 2-layer, 50 mm² per layer, 1 oz Cu, FR4 PCB. Heat sinking should be spread equally among all pins (caution: pin 2 must be electrically isolated).

NOTE: Normally this device would be mounted on the same copper heat sink and adjacent to the LED(s). If the LED(s) were to go open, then the HBL shunt would now dissipate the power using the same copper heat sink. Since the HBL has a voltage that is lower than that of the LED(s), then the power dissipation would be easily handled by the same heat sink as the LED.

ELECTRICAL CHARACTERISTICS (Unless otherwise noted: T_A = 25°C)

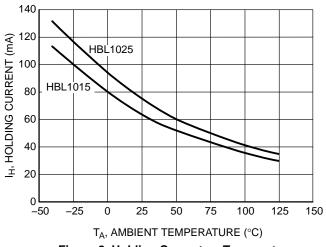
Symbol	Characteristics	Min	Min	Тур	Max	Unit
V _(BR)	Breakdown Voltage: The minimum voltage across the device in or at the breakdown region. Measured at $I_{BR} = 1$ mA.	HBL1015	8.0			V
		HBL1025	11.5			
lΗ	Holding Current: The minimum current required to maintain the device in the on-state.	HBL1015			125	mA
		HBL1025			125	
V _{BO}	Breakover Voltage: The voltage across the device in the breakover region. Measured at $I_{BO} = 10$ mA.	HBL1015			14.0	V
		HBL1025			16.0	
I _R	Off–State Current: The dc value of current that results from the application of the off-state voltage. This is measured at 8.0 V for	HBL1015			0.5	μΑ
	HBL1015 and 11.5 V for HBL1025.	HBL1025			0.5	1
V _T	On-State Voltage	HBL1015	1.2	1.8	2.4	V
		HBL1025	1.2	1.8	2.4	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL PERFORMANCE CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

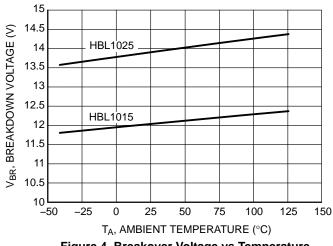
20



19 18 C_d, CAPACITANCE (pF) HBL1015 17 16 15 14 HBL1025 13 12 11 10 0 2 3 5 6 7 8 VOLTS (V)

Figure 2. Holding Current vs Temperature

Figure 3. Capacitance vs Voltage



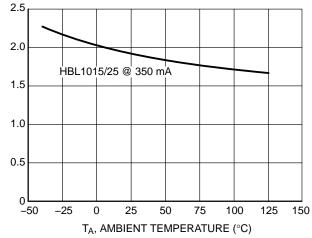
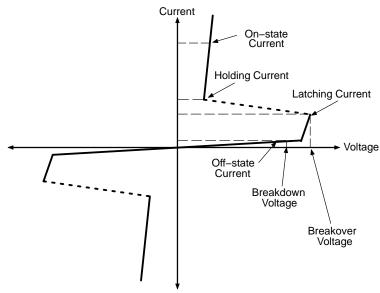


Figure 4. Breakover Voltage vs Temperature

Figure 5. On-State Voltage vs Temperature



V_T, ON-STATE VOLTAGE (V)

Figure 6. I-V Characteristics

TYPICAL APPLICATION CIRCUIT

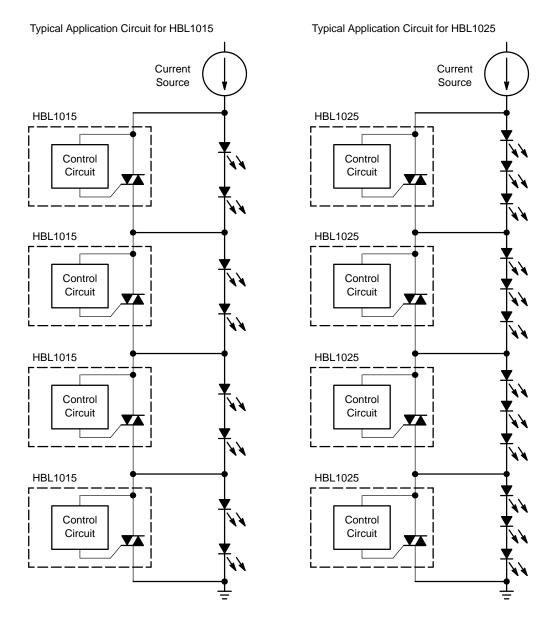


Figure 7. Typical Application Circuit

DEVICE ORDERING INFORMATION

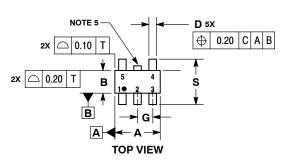
Device	Marking	Package	Shipping [†]
HBL1015T1G	015	TSOP-5 (Pb-Free)	3000 / Tape & Reel
HBL1025T1G	025	TSOP-5 (Pb-Free)	3000 / Tape & Reel

[†]For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

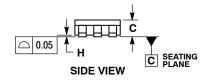


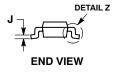
TSOP-5 **CASE 483 ISSUE N**

DATE 12 AUG 2020









NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE
 MINIMUM THICKNESS OF BASE MATERIAL.
- MINIMUM I HICKNESS OF BASE MAI EHIAL.

 DIMENSIONS A AND B DO NOT INCLUDE MOLD
 FLASH, PROTRUSIONS, OR GATE BURRS. MOLD
 FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT
 EXCEED 0.15 PER SIDE. DIMENSION A.

 OPTIONAL CONSTRUCTION: AN ADDITIONAL
- TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIMETERS		
DIM	MIN	MAX	
Α	2.85	3.15	
В	1.35	1.65	
C	0.90	1.10	
D	0.25	0.50	
G	0.95 BSC		
Н	0.01	0.10	
J	0.10	0.26	
K	0.20	0.60	
М	0 °	10 °	
S	2.50 3.00		

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*





XXX = Specific Device Code XXX = Specific Device Code

= Assembly Location = Date Code

= Year = Pb-Free Package

= Work Week W

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

DOCUMENT NUMBER:	98ARB18753C	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	TSOP-5		PAGE 1 OF 1	

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the

ON Semiconductor and ware trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and seven earnathy, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT
North American Technical Support:
Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

 \Diamond